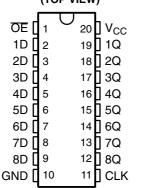
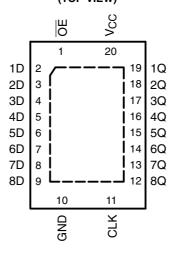
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- 2-V to 5.5-V V_{CC} Operation
- Max t_{pd} of 10 ns at 5 V
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 >2.3 V at V_{CC} = 3.3 V, T_A = 25°C
- Support Mixed-Mode Voltage Operation on All Ports
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

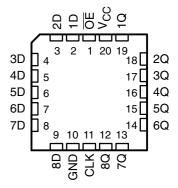
SN54LV574A . . . J OR W PACKAGE SN74LV574A . . . DB, DGV, DW, NS, OR PW PACKAGE (TOP VIEW)



SN74LV574A . . . RGY PACKAGE (TOP VIEW)



SN54LV574A . . . FK PACKAGE (TOP VIEW)



description/ordering information

ORDERING INFORMATION

T _A	PACKA	GE [†]	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Reel of 1000	SN74LV574ARGYR	LV574A
	0010 014	Tube of 25	SN74LV574ADW	11/5744
	SOIC - DW	Reel of 2000	SN74LV574ADWR	LV574A
	SOP – NS	Reel of 2000	SN74LV574ANSR	74LV574A
4000 to 0500	SSOP – DB	Reel of 2000	SN74LV574ADBR	LV574A
-40°C to 85°C		Tube of 70	SN74LV574APW	
	TSSOP - PW	Reel of 2000	SN74LV574APWR	LV574A
		Reel of 250	SN74LV574APWT	
	TVSOP - DGV	Reel of 2000	SN74LV574ADGVR	LV574A
	VFBGA – GQN	Reel of 1000	SN74LV574AGQNR	LV574A
	CDIP – J	Tube of 20	SNJ54LV574AJ	SNJ54LV574AJ
–55°C to 125°C	CFP – W	Tube of 85	SNJ54LV574AW	SNJ54LV574AW
	LCCC - FK	Tube of 55	SNJ54LV574AFK	SNJ54LV574AFK

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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description/ordering information (continued)

The 'LV574A devices are octal edge-triggered D-type flip-flops designed for 2-V to 5.5-V V_{CC} operation.

These devices feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. The devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels set up at the data (D) inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

OE does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

0000

D

Ε

terminal assignments

	1	2	3	4
Α	1D	ŌĒ	V_{CC}	1Q
В	3D	3Q	2D	2Q
С	5D	4D	5Q	4Q
D	7D	7Q	6D	6Q
E	GND	8D	CLK	8Q

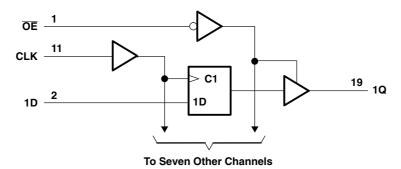
FUNCTION TABLE (each flip-flop)

	INPUTS		OUTPUT
ŌΕ	CLK	D	Q
L	1	Н	Н
L	\uparrow	L	L
L	H or L	Χ	Q_0
Н	X	Χ	Z



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logic diagram (positive logic)



Pin numbers shown are for the DB, DGV, DW, FK, J, NS, PW, RGY, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		–0.5 V to 7 V
)	
Voltage range applied to any output	t in the high-impedance	
or power-off state, VO (see Note	1)	–0.5 V to 7 V
Output voltage range applied in the	high or low state, V _O (see Notes 1 and 2)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$)		–20 mA
Output clamp current, I _{OK} (V _O < 0)		–50 mA
Continuous output current, IO (VO =	: 0 to V _{CC})	±35 mA
Continuous current through V _{CC} or	GND	±70 mA
Package thermal impedance, θ _{JA} (s	see Note 3): DB package	70°C/W
(s	see Note 3): DGV package	92°C/W
(s	see Note 3): DW package	58°C/W
(s	see Note 3): GQN package	78°C/W
(s	see Note 3): NS package	60°C/W
(s	see Note 3): PW package	83°C/W
(s	see Note 4): RGY package	37°C/W
Storage temperature range, T _{stq}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. This value is limited to 5.5 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.
- 4. The package thermal impedance is calculated in accordance with JESD 51-5.



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recommended operating conditions (see Note 5)

				SN54L	V574A	SN74L	/574A	
				MIN	MAX	MIN	MAX	UNIT
V_{CC}	Supply voltage			2	5.5	2	5.5	V
		$V_{CC} = 2$	2 V	1.5		1.5		
.,	I Bada Jawa Library Awadha wa	$V_{CC} = 2$	2.3 V to 2.7 V	$V_{CC} \times 0.7$		$V_{CC} \times 0.7$.,
V_{IH}	High-level input voltage	$V_{CC} = 3$	3 V to 3.6 V	$V_{CC} \times 0.7$		$V_{CC} \times 0.7$		V
		$V_{CC} = 4$	4.5 V to 5.5 V	$V_{CC} \times 0.7$		$V_{CC} \times 0.7$		
		$V_{CC} = 2$	2 V		0.5		0.5	
.,	Lave lavel beauties to as	$V_{CC} = 2$	2.3 V to 2.7 V		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	V
V_{IL}	Low-level input voltage	$V_{CC} = 3$	3 V to 3.6 V		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	V
		$V_{CC} = 4$	4.5 V to 5.5 V		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	
VI	Input voltage			0	5.5	0	5.5	V
	Outratualla	顶点光电学商	pw state	0	V _{CC}	0	V_{CC}	V
V_{O}	Output voltage		ertex-icbuy.co	n/ o	5.5	0	5.5	V
		$V_{CC} = 2$	2 V		-50		-50	μΑ
	High lavel autout august	$V_{CC} = 2$	2.3 V to 2.7 V	2	-2		-2	
l _{OH}	High-level output current	$V_{CC} = 3$	3 V to 3.6 V	20%	-8		-8	mA
		$V_{CC} = 4$	4.5 V to 5.5 V	Q	-16		-16	
		$V_{CC} = 2$	2 V		50		50	μΑ
	Lave lavel autout avenue	$V_{CC} = 2$	2.3 V to 2.7 V		2		2	
l _{OL}	Low-level output current	$V_{CC} = 3$	3 V to 3.6 V		8		8	mA
		$V_{CC} = 4$	4.5 V to 5.5 V		16		16	
		$V_{CC} = 2$	2.3 V to 2.7 V		200		200	
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3$	3 V to 3.6 V		100		100	ns/V
		$V_{CC} = 4$	4.5 V to 5.5 V		20		20	
T _A	Operating free-air temperature	-		-55	125	-40	85	°C

NOTE 5: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

24244555	TTOT COMPITIONS		SN54LV5	74A	SN74	ILV574A	Ļ	
PARAMETER	TEST CONDITIONS	V _{CC}	MIN TY	P MAX	MIN	TYP	MAX	UNIT
	$I_{OH} = -50 \mu A$	2 V to 5.5 V	V _{CC} -0.1		V _{CC} -0.1			
V	$I_{OH} = -2 \text{ mA}$	2.3 V	2		2			V
V _{OH}	$I_{OH} = -8 \text{ mA}$	3 V	2.48		2.48			V
	$I_{OH} = -16 \text{ mA}$	4.5 V	3.8	N. Carlotte	3.8			
	$I_{OL} = 50 \mu A$	2 V to 5.5 V	3/2	0.1			0.1	
V	$I_{OL} = 2 \text{ mA}$	2.3 V	W _G	0.4			0.4	V
V_{OL}	I _{OL} = 8 mA	3 V	16	0.44			0.44	V
	I _{OL} = 16 mA	4.5 V	¹ / ₁ C	0.55			0.55	
II	$V_I = 5.5 \text{ V or GND}$	0 to 5.5 V	0	±1			±1	μΑ
l _{OZ}	$V_O = V_{CC}$ or GND	5.5 V	Q'	±5			±5	μΑ
I _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V		20			20	μΑ
I _{off}	V_I or $V_O = 0$ to 5.5 V	0		5			5	μΑ
C _i	V _I = V _{CC} or GND	3.3 V	1	.8		1.8		pF

PRODUCT PREVIEW information concerns products in the formative or design phase of development. Characteristic data and other specifications are design goals. Texas Instruments reserves the right to change or discontinue these products without notice.



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timing requirements over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

	DADAMETED		$T_A = 2$	25°C	SN54L	V574A	SN74L\	/574A	
	PARAMETER		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _w	Pulse duration	CLK high or low	7		7	100	7		ns
t _{su}	Setup time	High or low before CLK↑	5.5		5.5	JIP.	5.5		ns
t _h	Hold time	Data after CLK↑	2		2		2		ns

timing requirements over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

	PARAMETER				SN54LV574A		SN74LV574A		LIMIT
	PARAMETER		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _w	Pulse duration	CLK high or low	5		5	10,01	5		ns
t _{su}	Setup time	High or low before CLK↑	3.5		3.5	11/2	3.5		ns
t _h	Hold time	Data after CLK↑	1.5		1.5		1.5		ns

timing requirements over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

	DADAMETED		T _A = 2	25°C	SN54L	/574A	SN74L\	/574A	LINIT
	PARAMETER		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _w	Pulse duration	CLK high or low	5		5	10,01	5		ns
t _{su}	Setup time	High or low before CLK↑	3.5		3.5	1115	3.5		ns
t _h	Hold time	Data after CLK↑	1.5		1.5		1.5		ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

DADAMETED	FROM	то	LOAD	T,	д = 25°C	;	SN54L\	/574A	SN74L\	/574A	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			C _L = 15 pF	60*	100*		50*		50		N 41 1-
f _{max}			C _L = 50 pF	50	85		40	N	40		MHz
t _{pd}	CLK	Q			9.6*	16.6*	1*	20*	1	20	
t _{en}	ŌĒ	Q	C _L = 15 pF		9.2*	16.1*	1* 2	19*	1	19	ns
t _{dis}	ŌĒ	Q			6.5*	12.8*	15	15*	1	15	
t _{pd}	CLK	Q			11.6	19.6	$ Q_{Q_{Q_{Q_{Q_{Q_{Q_{Q_{Q_{Q_{Q_{Q_{Q_{$	23	1	23	
t _{en}	ŌĒ	Q	0 50 5		10.9	19	ر الا	22	1	22	
t _{dis}	ŌĒ	Q	$C_L = 50 pF$		8.4	17.5	1	20	1	20	ns
t _{sk(o)}						2				2	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

DADAMETED	FROM	то	LOAD	T,	_A = 25°C	;	SN54L	V574A	SN74L	/574A	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			C _L = 15 pF	80*	145*		65*		65		N 41 1-
f _{max}			C _L = 50 pF	50	120		45		45		MHz
t _{pd}	CLK	Q			6.8*	13.2*	1*	15.5*	1	15.5	
t _{en}	ŌĒ	Q	C _L = 15 pF		6.4*	12.8*	1*	15*	1	15	ns
t _{dis}	ŌĒ	Q			4.8*	13*	1*,	15*	1	15	
t _{pd}	CLK	Q			8.1	16.7	2/2	19	1	19	
t _{en}	ŌĒ	Q	0 50 5		7.7	16.3	0/1	18.5	1	18.5	
t _{dis}	ŌĒ	Q	$C_L = 50 pF$		6.1	15	Q 1	17	1	17	ns
t _{sk(o)}						1.5				1.5	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

	FROM	то	LOAD	T,	_A = 25°C	;	SN54L	V574A	SN74LV	/574A	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			C _L = 15 pF	130*	205*		110*		110		N.41.1-
f _{max}			C _L = 50 pF	85	175		75	_	75		MHz
t _{pd}	CLK	Q			4.8*	8.6*	1*	10*	1	10	
t _{en}	ŌĒ	Q	C _L = 15 pF		4.6*	9*	1*	10.5*	1	10.5	ns
t _{dis}	ŌĒ	Q			3.5*	9*	1*	10.5*	1	10.5	
t _{pd}	CLK	Q			5.7	10.6	27/2	12	1	12	
t _{en}	ŌĒ	Q	0 50 5		5.5	11	0 1	12.5	1	12.5	
t _{dis}	ŌĒ	Q	C _L = 50 pF		4.1	10.1	Q 1	11.5	1	11.5	ns
t _{sk(o)}						1				1	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, $V_{CC} = 3.3 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 6)

	DADAMETED	SN	SN74LV574A			
	PARAMETER	MIN	TYP	MAX	UNIT	
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.7	8.0	V	
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.6	-0.8	V	
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		2.8		V	
V _{IH(D)}	High-level dynamic input voltage	2.31			V	
V _{IL(D)}	Low-level dynamic input voltage			0.99	V	

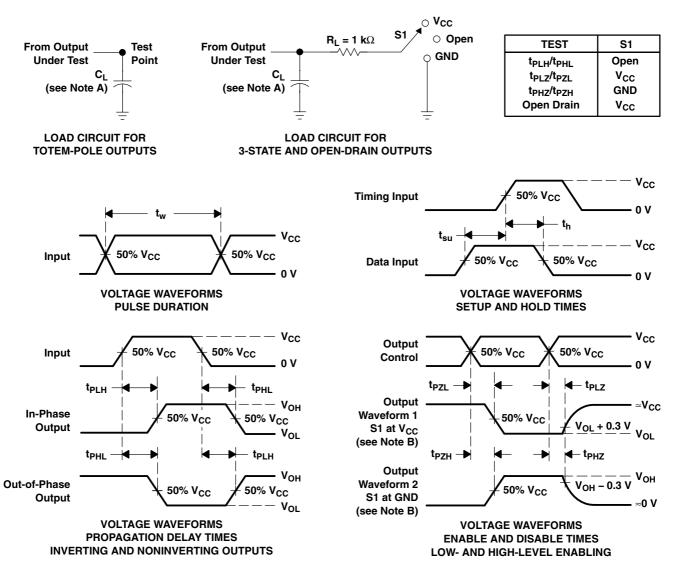
NOTE 6: Characteristics are for surface-mount packages only.

operating characteristics, T_A = 25°C

	PARAMETER				TEST CONDITIONS			UNIT
	C _{pd}	Power dissipation capacitance	Outputs enabled	C 50 pE	f _ 10 MU=	3.3 V	20.4	pF
				$C_L = 50 \text{ pF},$	f = 10 MHz	5 V	23.8	



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq 3$ ns. $t_f \leq 3$ ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PHL} and t_{PLH} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

PACKAGE OPTION ADDENDUM

13-Aug-2021

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LV574ADBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV574A	Samples
SN74LV574ADGVR	ACTIVE	TVSOP	DGV	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV574A	Samples
SN74LV574ADW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV574A	Samples
SN74LV574ADWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV574A	Samples
SN74LV574ANSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	74LV574A	Samples
SN74LV574APW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV574A	Samples
SN74LV574APWG4	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV574A	Samples
SN74LV574APWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV574A	Samples
SN74LV574APWT	ACTIVE	TSSOP	PW	20	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV574A	Samples
SN74LV574ARGYR	ACTIVE	VQFN	RGY	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LV574A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: Til defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



PACKAGE OPTION ADDENDUM

13-Aug-2021

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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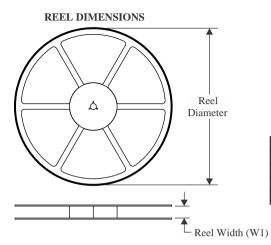
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION



3-Jun-2022

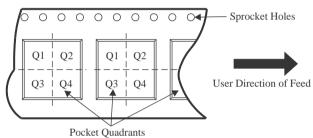
TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 + P1 + B0 W Cavity - A0 +

A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



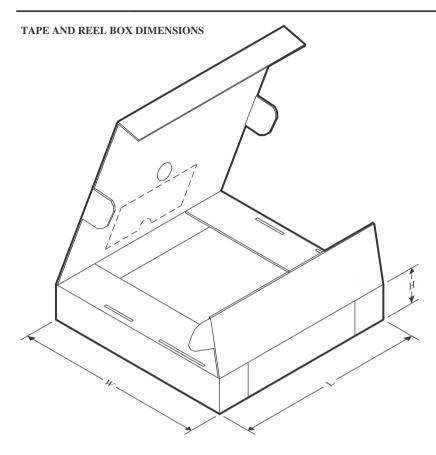
*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV574ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LV574ADGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV574ANSR	so	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LV574APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LV574APWT	TSSOP	PW	20	250	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LV574ARGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION



3-Jun-2022



*All dimensions are nominal

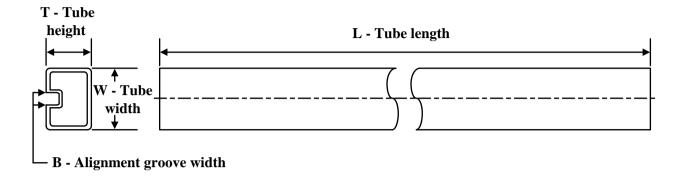
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV574ADBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74LV574ADGVR	TVSOP	DGV	20	2000	356.0	356.0	35.0
SN74LV574ANSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LV574APWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74LV574APWT	TSSOP	PW	20	250	356.0	356.0	35.0
SN74LV574ARGYR	VQFN	RGY	20	3000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION



3-Jun-2022

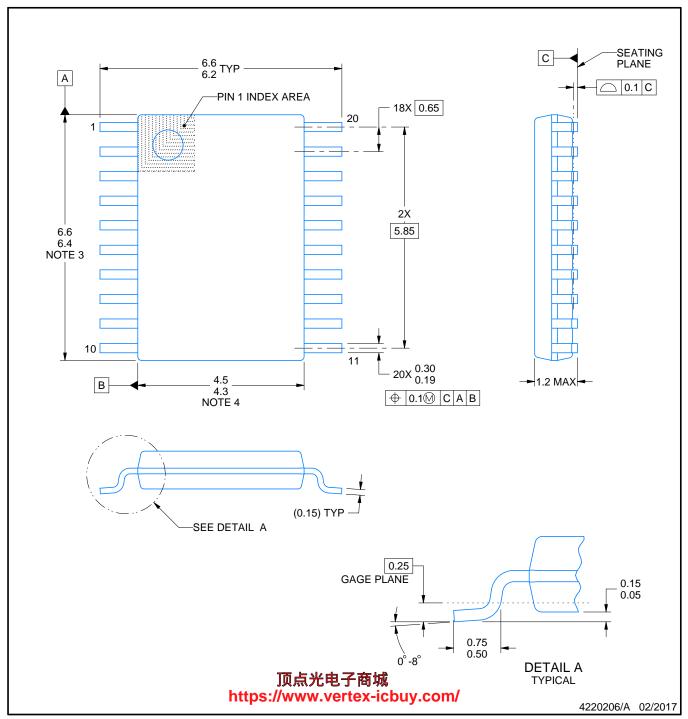
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74LV574ADW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74LV574APW	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74LV574APWG4	PW	TSSOP	20	70	530	10.2	3600	3.5





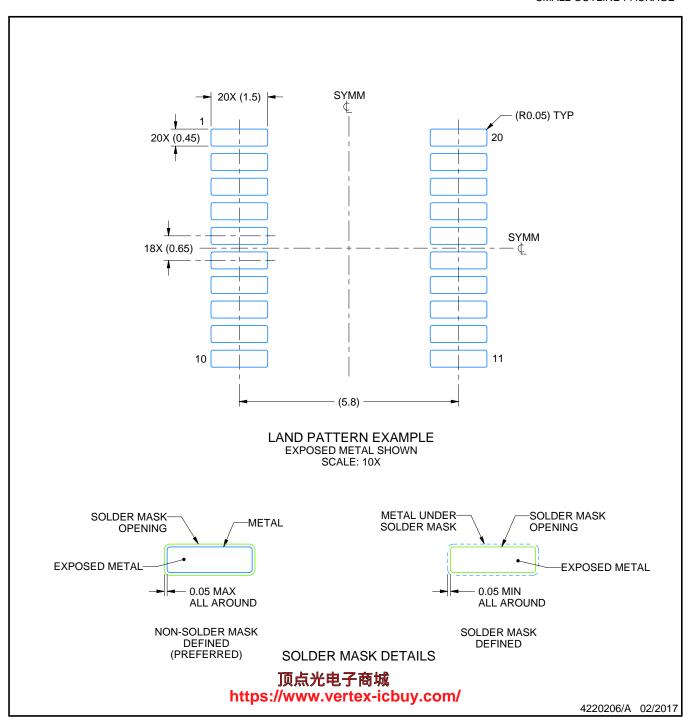
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



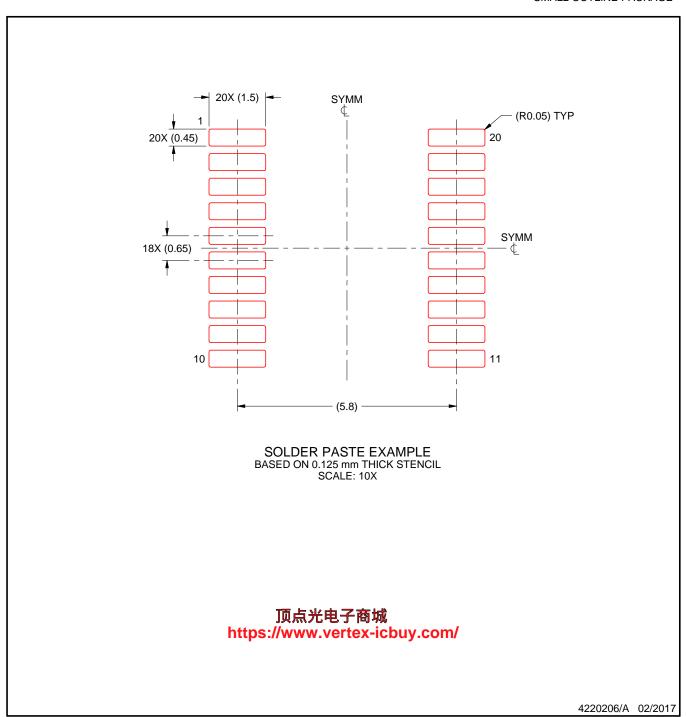


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





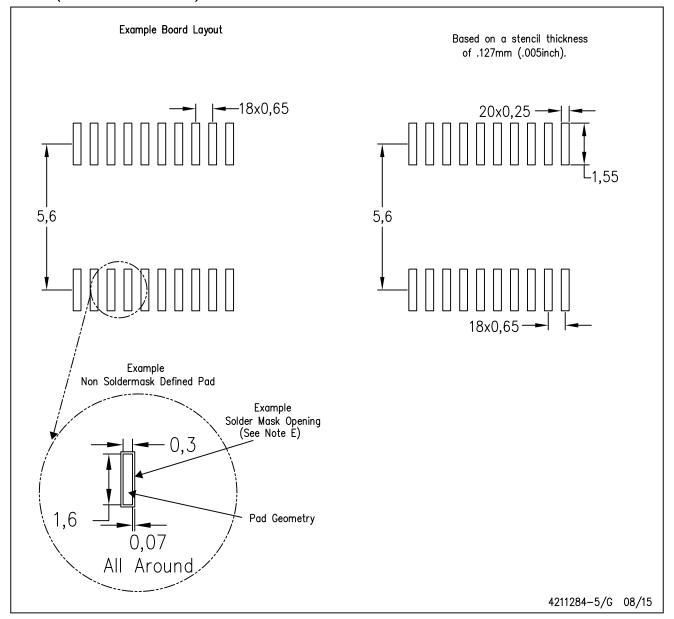
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE

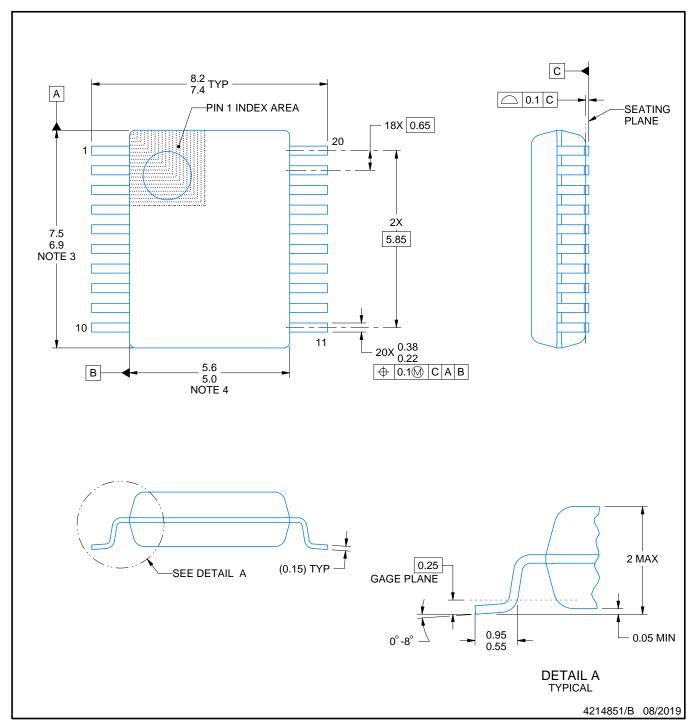


NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

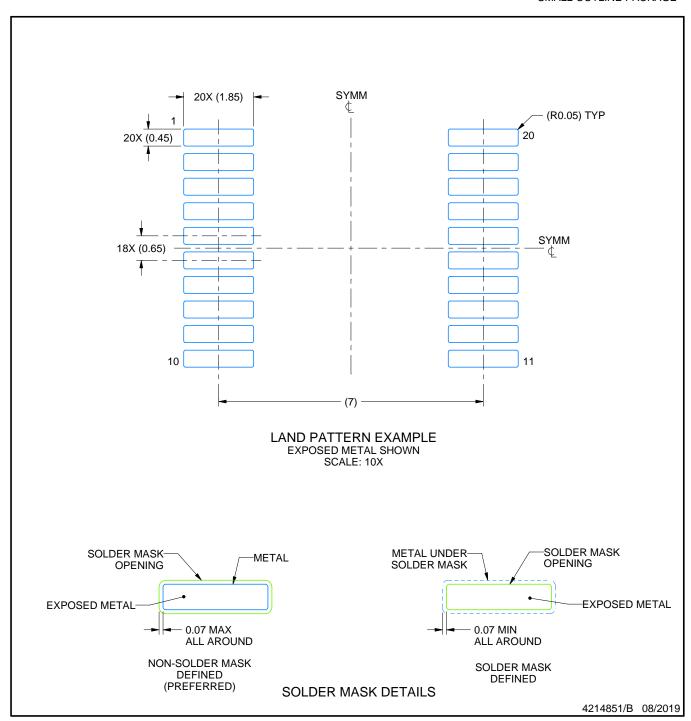
 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.

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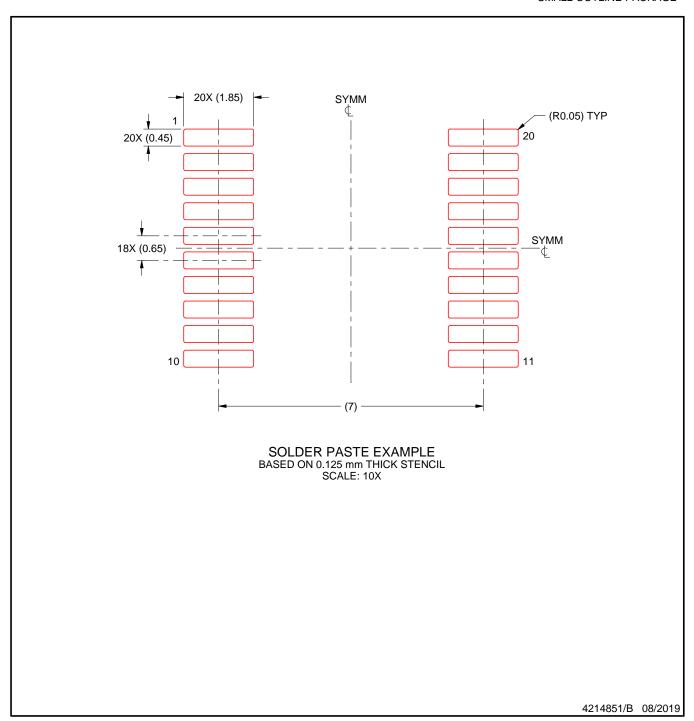


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.

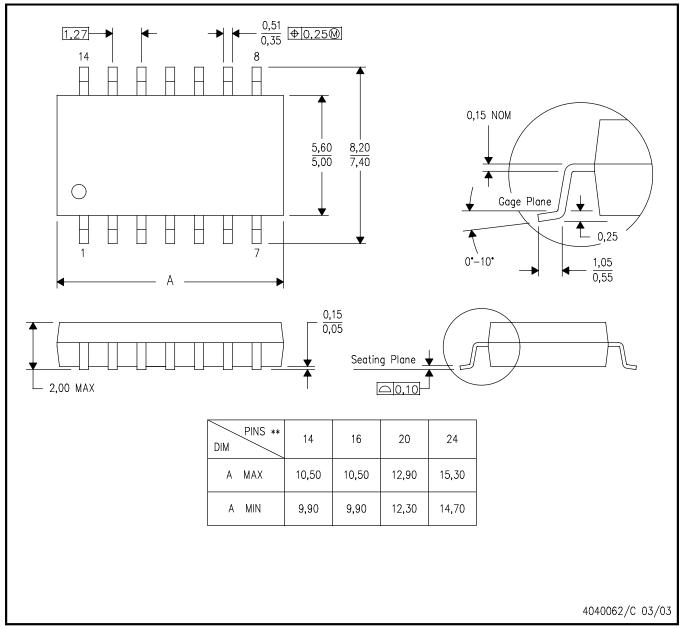


MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

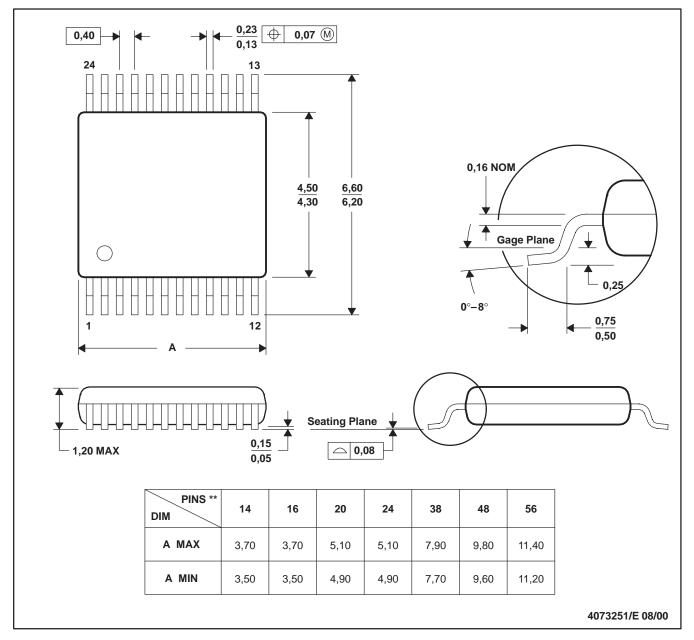
- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153

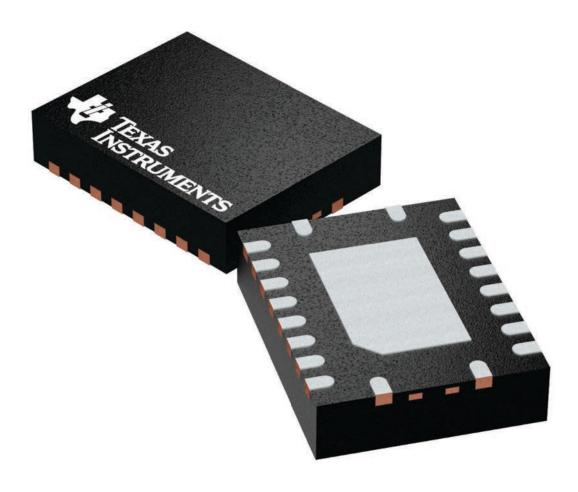
14/16/20/56 Pins - MO-194



3.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FGLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



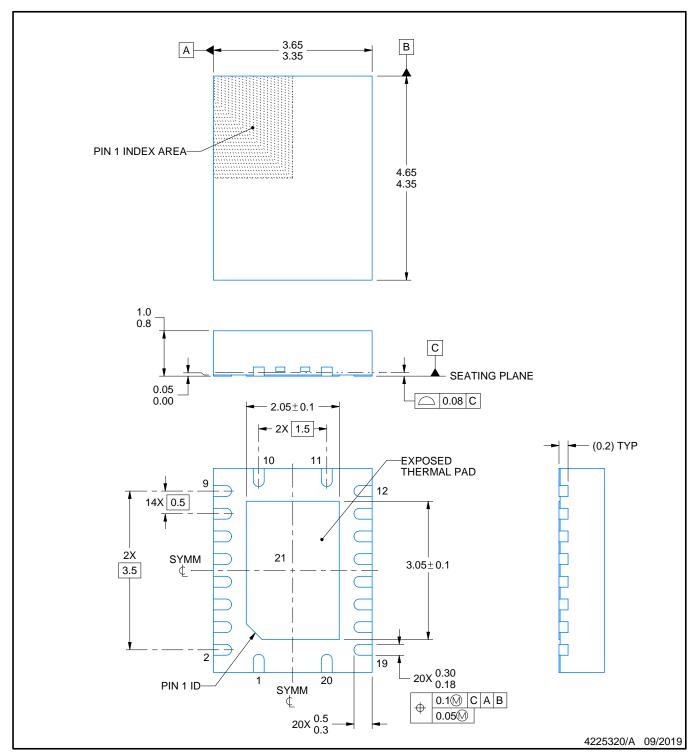
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PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

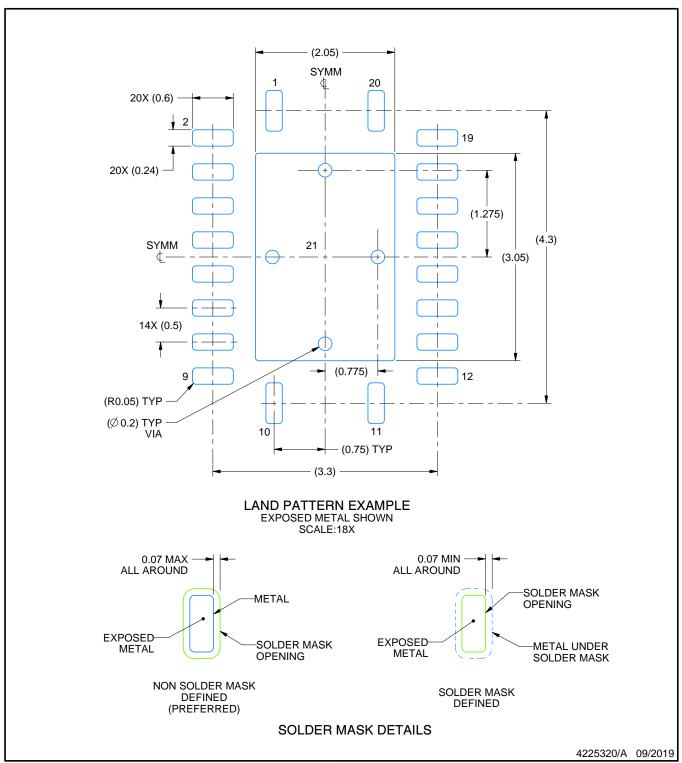
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance. 顶点光电子商城

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PLASTIC QUAD FLATPACK - NO LEAD

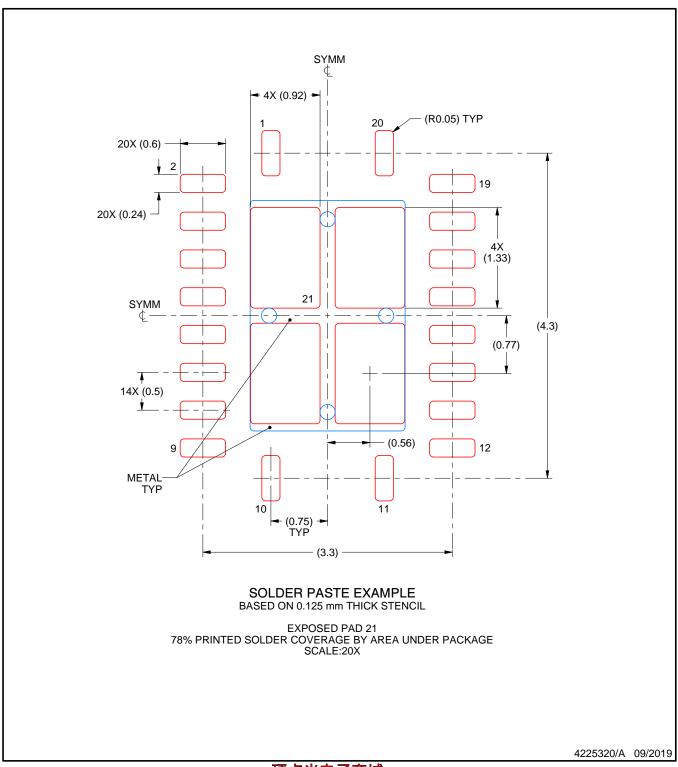


NOTES: (continued)

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 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

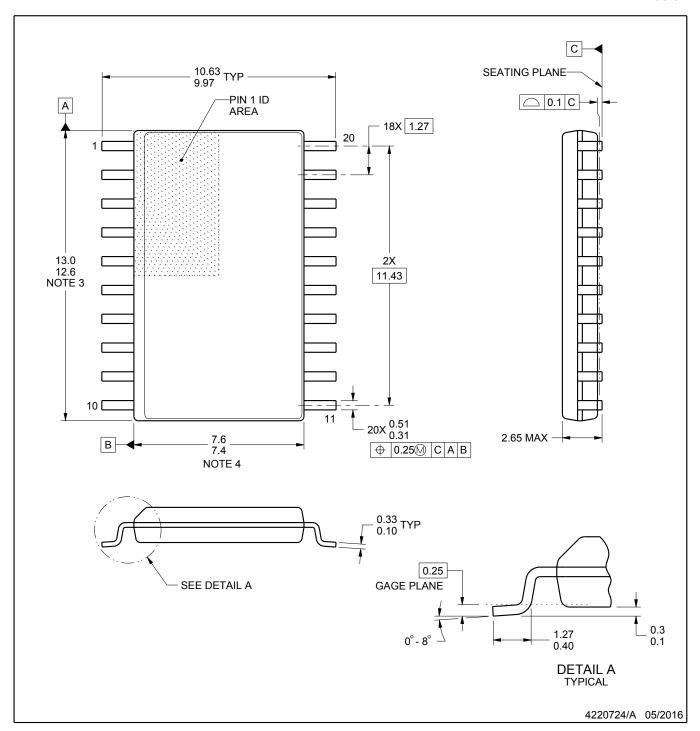
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6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

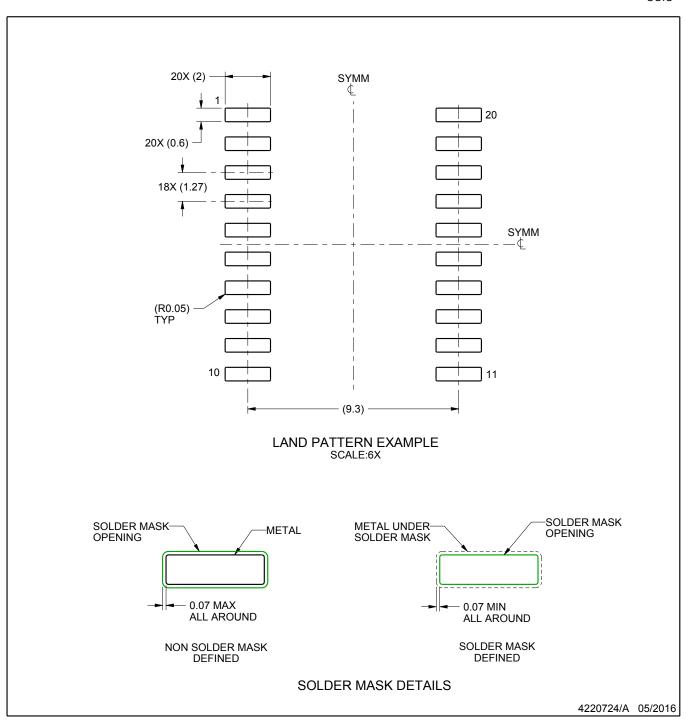
 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.

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SOIC

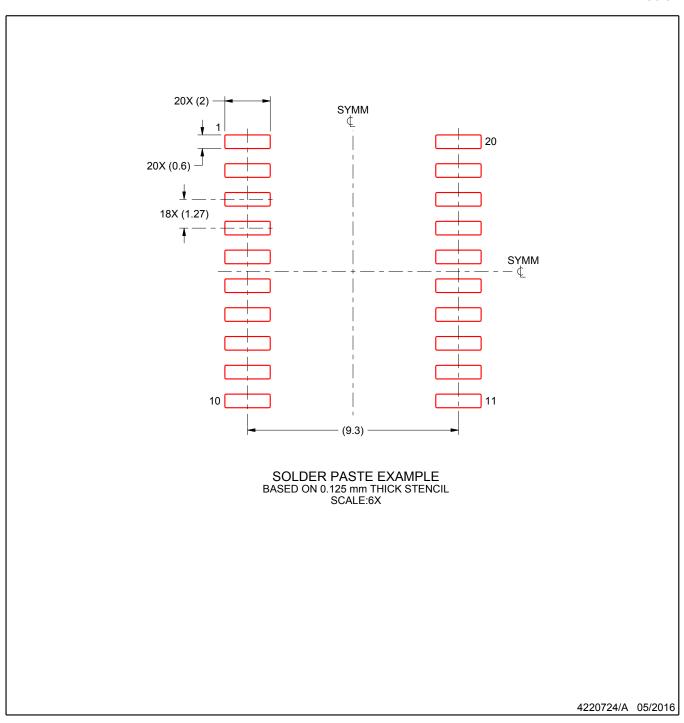


NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.

